

TRIPLE DIFFUSED PLANER TYPE HIGH SPEED SWITCHING

■ Features

- High voltage, High speed switching
- Low saturation voltage
- High reliability

■ Applications

- Switching regulators
- DC-DC convertor
- Solid State Relay
- General purpose power amplifiers

■ Maximum ratings and characteristics

● Absolute maximum ratings (Tc=25°C unless otherwise specified)

Item	Symbol	Ratings	Unit
Collector-Base voltage	V _{CB0}	250	V
Collector-Emitter voltage	V _{CEO}	200	V
Collector-Emitter voltage	V _{CEO(SUS)}	200	V
Emitter-Base voltage	V _{EBO}	7	V
Collector current	I _C	10	A
Base current	I _B	5	A
Collector power dissipation	P _C	100	W
Operating junction temperature	T _j	+150	°C
Storage temperature	T _{stg}	-55 to +150	°C

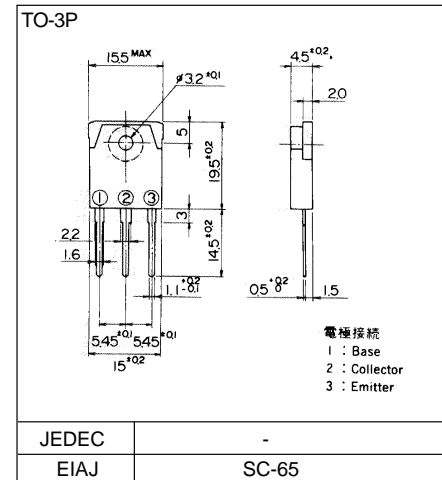
● Electrical characteristics (Tc =25°C unless otherwise specified)

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Base voltage	V _{CB0}	I _{CBO} = 0.1mA	250			V
Collector-Emitter voltage	V _{CEO}	I _{CEO} = 10mA	200			V
Collector-Emitter voltage	V _{CEO(SUS)}	I _C = 1A	200	-		V
Emitter-Base voltage	V _{EBO}	I _{EBO} = 0.1mA	7	-		V
Collector-Base leakage current	I _{CBO}	V _{CB0} = 250V		-	0.1	mA
Emitter-Base leakage current	I _{EBO}	V _{EBO} = 7V		-	0.1	mA
D.C. current gain	h _{FE}	I _C = 2A, V _{CE} = 5V	20		60	
Collector-Emitter saturation voltage	V _{CE(Sat)}	I _C = 2A, I _B = 0.8A			0.2	V
Base-Emitter saturation voltage	V _{BE(Sat)}	I _C = 5A, I _B = 1A			1.1	V
*1	t _{on}	I _C = 6A, I _{B1} = -I _{B2} = 1.2A			0.8	μs
Switching time	t _{stg}	R _L = 10 ohm, P _w = 20μs Duty=<2%			2.0	μs
	t _f				0.5	μs

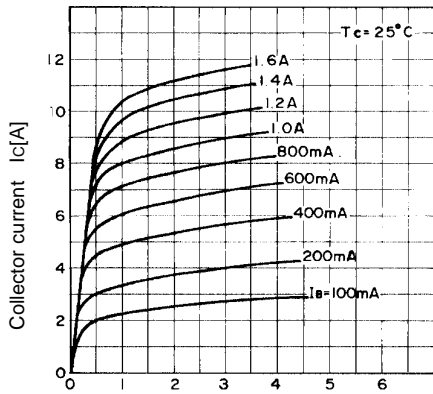
● Thermal characteristics

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal resistance	R _{th(j-c)}	Junction to case			1.25	°C/W

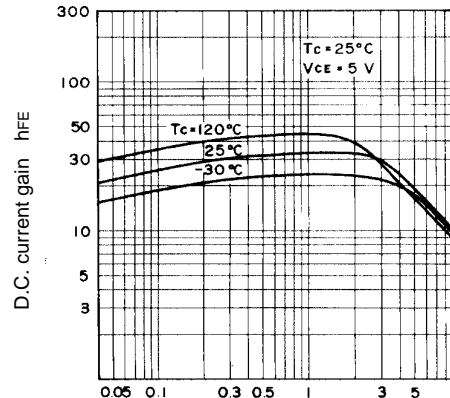
■ Outline Drawings



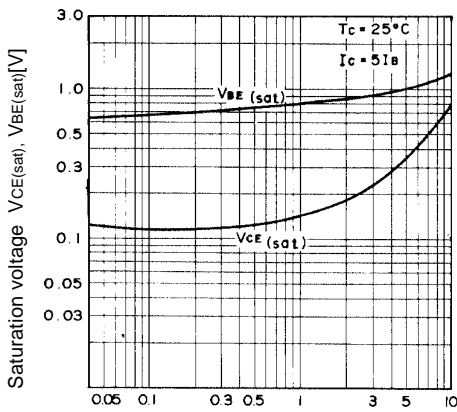
Characteristics



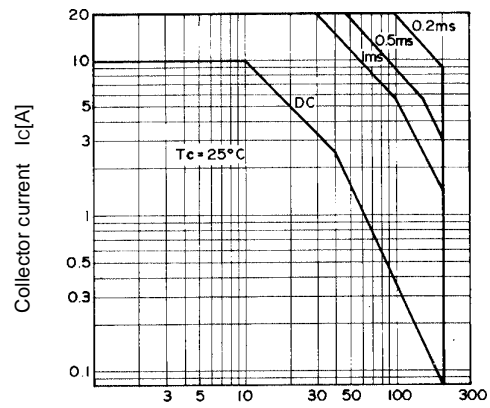
Collector Output Characteristics



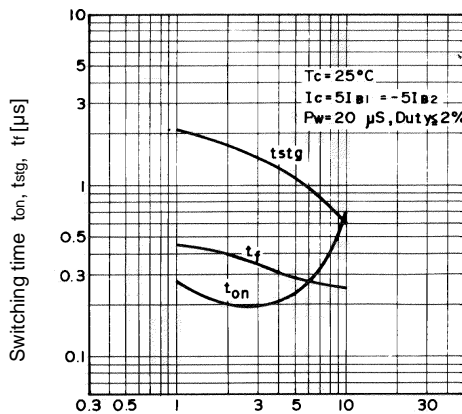
DC Current Gain



Base and Collector Saturation Voltage



Safe Operating Area



Switching Time

*1 Switching Time Test Circuit

